

## Description

The SM3415SRL uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

### **General Features**

 $V_{DS} = -20V \ I_D = -4.1A$  $R_{DS(ON)} < 45m\Omega@ V_{GS} = -4.5V$ ESD Rating: 1500V HBM

## Application

Battery protection Load switch Uninterruptible power supply

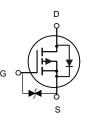
### **Package Marking and Ordering Information**

Product ID	Pack	Brand	Qty(PCS)
SM3415SRL	SOT-23-3L	HXY MOSFET	3000

### Absolute Maximum Ratings (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

Symbol	Parameter	Limit	Unit	
VDS	Drain-Source Voltage	-20	V	
Vgs	Gate-Source Voltage	±10	V	
ID	Drain Current-Continuous	-4.1	A	
Ідм	Drain Current-Pulsed <sup>(Note 1)</sup>	-30	A	
PD	Maximum Power Dissipation	1.4	W	
Тյ,Тѕтс	Operating Junction and Storage Temperature Range	-55 To 150	°C	
Reja	Thermal Resistance, Junction-to-Ambient (Note 2)	89.3	°C/W	





P-Channel MOSFET

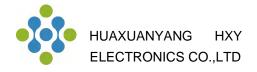


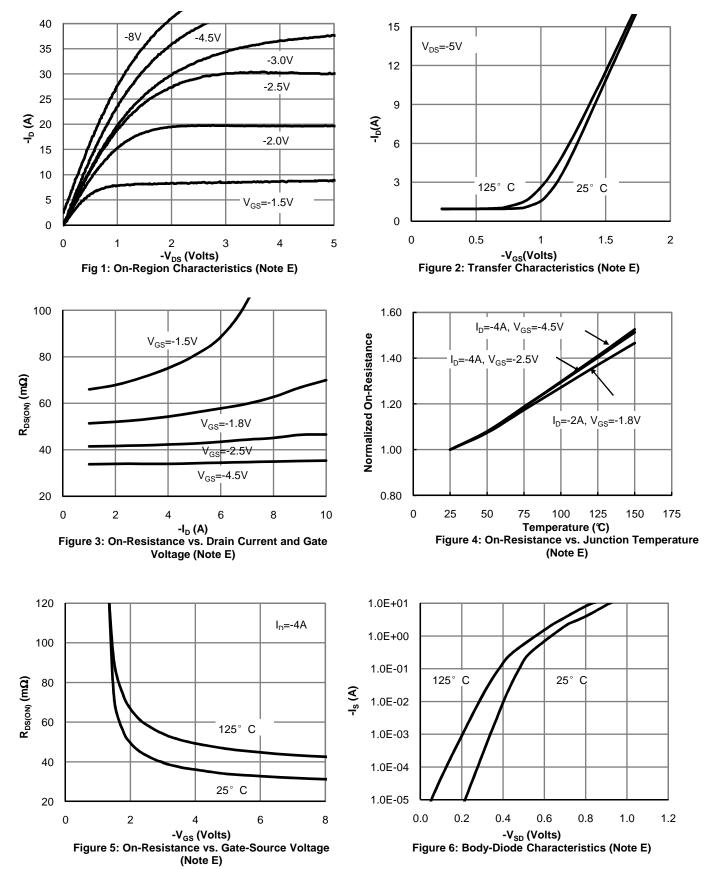
## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

•		-				
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±10V,V <sub>DS</sub> =0V	-	-	±10	μA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250µA	-0.35	-0.55	-0.9	V
Durain Courses On State Desistence	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-4A	-	34	45	mΩ
Drain-Source On-State Resistance		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-4A	-	44	60	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =-5V,I <sub>D</sub> =-4A	8	-	-	S
Dynamic Characteristics (Note4)		·				
Input Capacitance	Clss	V <sub>DS</sub> =-10V,V <sub>GS</sub> =0V,	-	950	-	PF
Output Capacitance	Coss		-	165	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	120	-	PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t <sub>d(on)</sub>		-	12		nS
Turn-on Rise Time	tr	V <sub>DD</sub> =-10V,R <sub>L</sub> =2. 5Ω V <sub>GS</sub> =-4.5V,R <sub>GEN</sub> =3Ω	-	10		nS
Turn-Off Delay Time	t <sub>d(off)</sub>		-	19		nS
Turn-Off Fall Time	t <sub>f</sub>		-	25		nS
Total Gate Charge	Qg	V <sub>DS</sub> =-10V,I <sub>D</sub> =-4A,	-	12		nC
Gate-Source Charge	Q <sub>gs</sub>		-	1.4	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =-4.5V	-	3.6	-	nC
Drain-Source Diode Characteristics			- <b>I</b>			
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-4A	-	-	-1.2	V
Diode Forward Current (Note 2)	Is		-	-	-4	А

#### Notes:

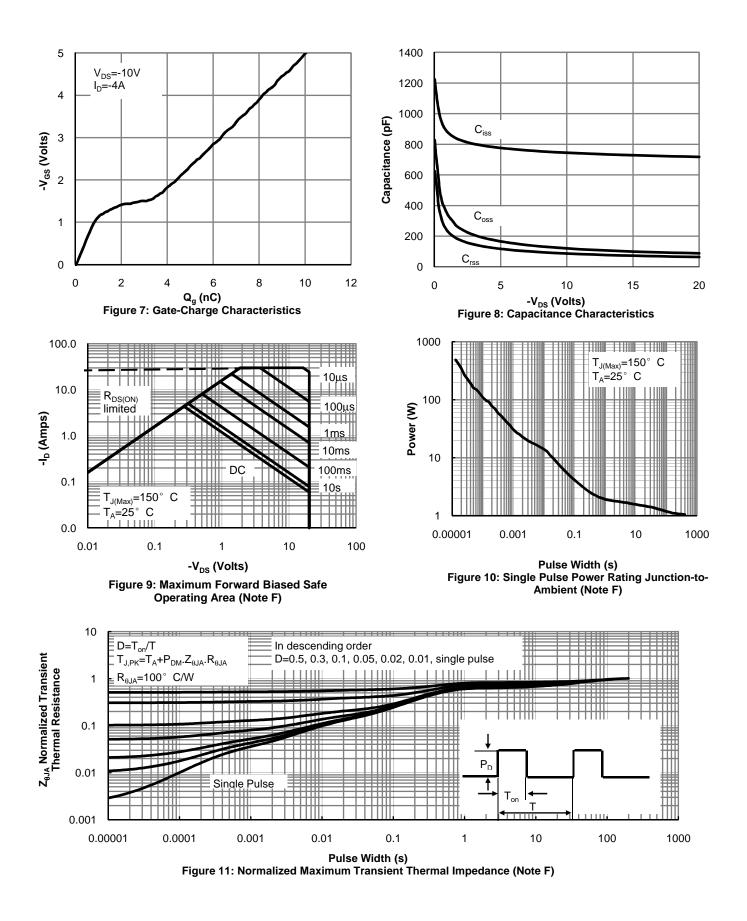
- **1.** Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- **3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production

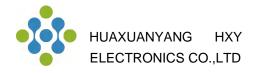




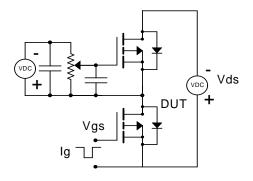
## **Typical Electrical and Thermal Characteristics**

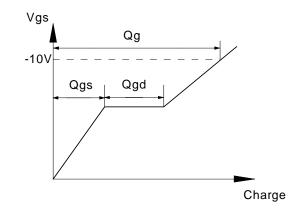




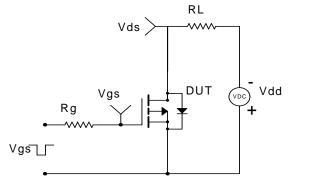


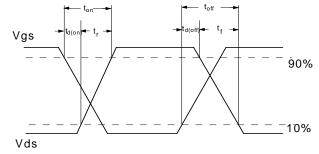
## Gate Charge Test Circuit & Waveform

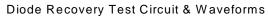


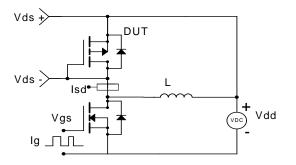


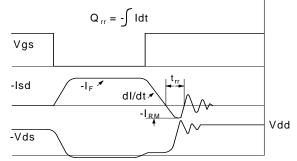
Resistive Switching Test Circuit & Waveforms





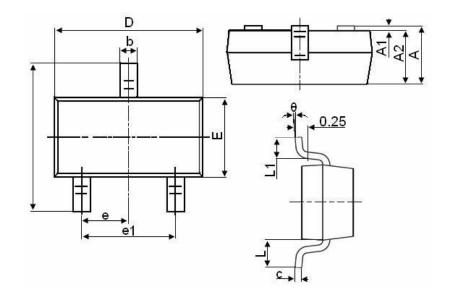








# SOT-23-3L Package Information



Symbol	Dimensions in Millimeters			
	MIN.	MAX.		
A	1.050	1.250		
A1	0.000	0.100		
A2	1.050	1.150		
b	0.300	0.500		
С	0.100	0.200		
D	2.800	3.000		
E	1.500	1.700		
E1	2.650	2.950		
е		0.950TYP		
e1	1.800	2.000		
L	0.550REF			
L1	0.300	0.600		
θ	0°	8°		



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